

Progress Towards Enabling Quantum Engineering

Photonics for Quantum (PfQ) Workshop

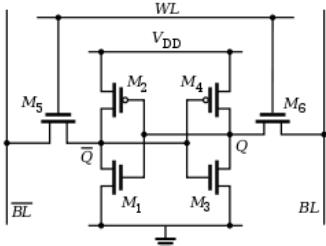
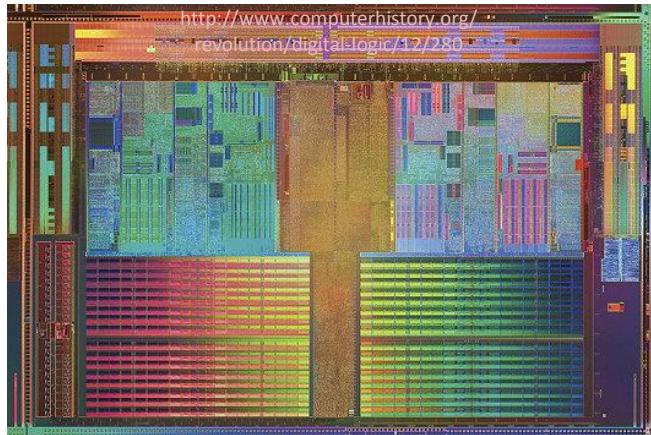
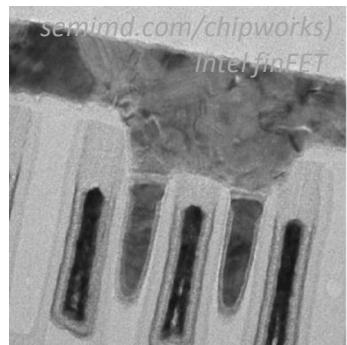
RIT, Rochester, January 23-25, 2018

*S. Olson, C. Hobbs, H. Chong, J. Nalaskowski, H. Stamper, J. Mucci, B. Martinick,
K. Beckmann, I. Wells, C. Johnson, V. Kaushik, T. Murray, S. Novak, S. Bennett, M. Rodgers,
C. Borst, M. Liehr and Satyavolu 'Pops' Papa Rao*

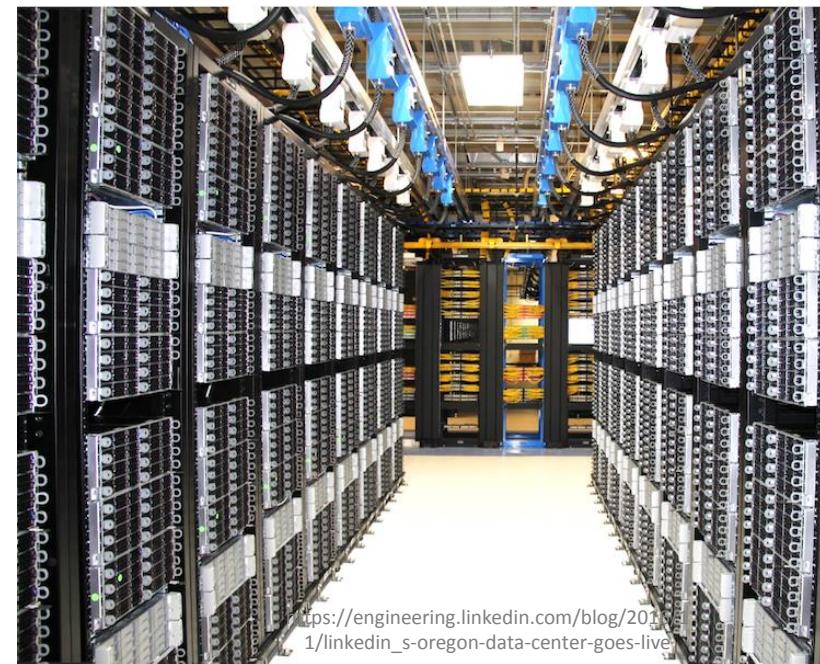
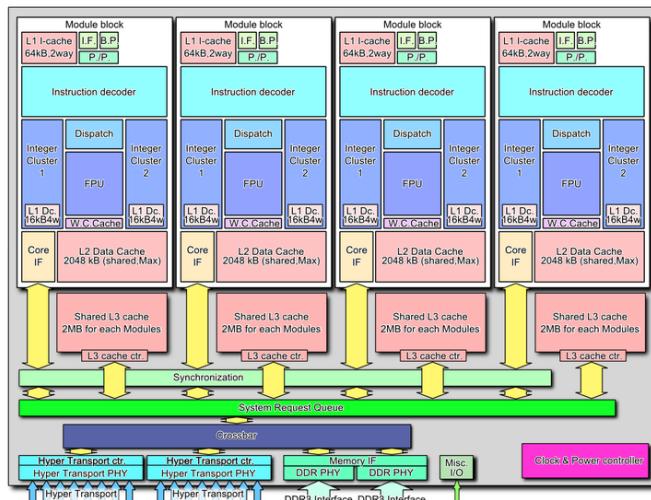
- **Thanks to our partners:**

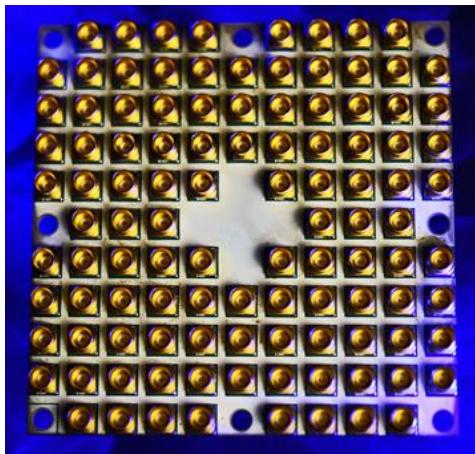
- University of Maryland/LPS (Kevin Osborn, Neda Forouzani, Steven Anlage)
- Syracuse University (Britton Plourde, Matt LaHaye)
- NIST Boulder (Jeff Shainline, Sonia Buckley, Richard Mirin, Sae Woo Nam)
- NIST Boulder (Dave Pappas)
- AFRL (Joe van Nostrand, Mike Fanto, Paul Alsing, Kathy-Anne Soderberg)
- Auburn University (Mike Hamilton, Mark Adams)
- Hypres (Oleg Mukhanov, Igor Vernik, Patrick Truitt)
- Yale (Rob Schoelkopf, Hong Tang, Fengnian Xia)
- Stony Brook University (Xu Du, Dmitri Averin)
- U. Rochester (Mishkat Bhattacharya)
- RIT (Stefan Preble)
- MIT (Dirk Englund)
- William & Mary (Seth Aubin)
- U. Maryland (Qudsia Quraishi)

- Order! Order!

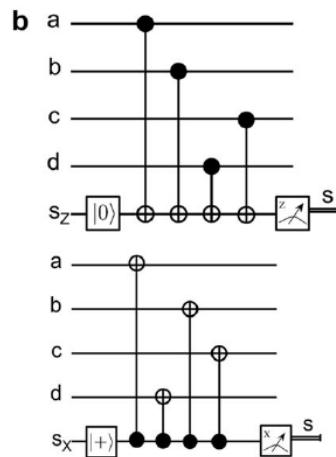


https://en.wikipedia.org/wiki/Static_random-access_memory





<https://newsroom.intel.com/news/intel-advances-quantum-neuromorphic-computing-research/>



Gambetta et al,
npj Quantum Information (2017) 3:2

```
// Create some entanglement that we
PrepareEntangledPair(here, there);

// Move our message into the entang
pNOT(msg, here);
H(msg);
```

From <https://www.microsoft.com/en-us/quantum/development-kit>

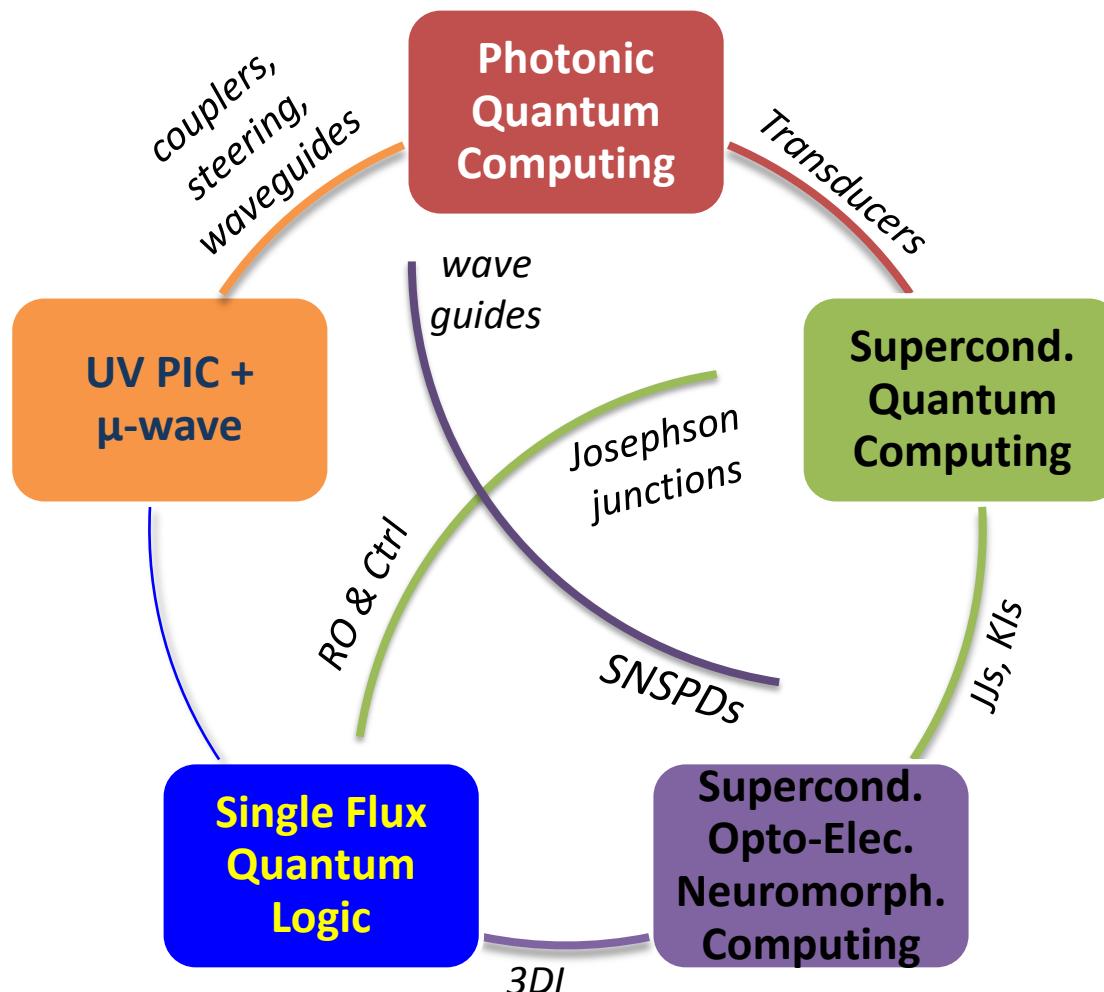


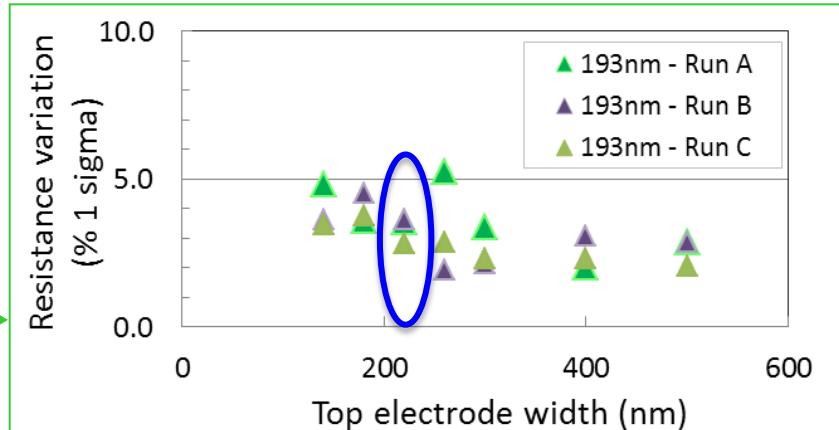
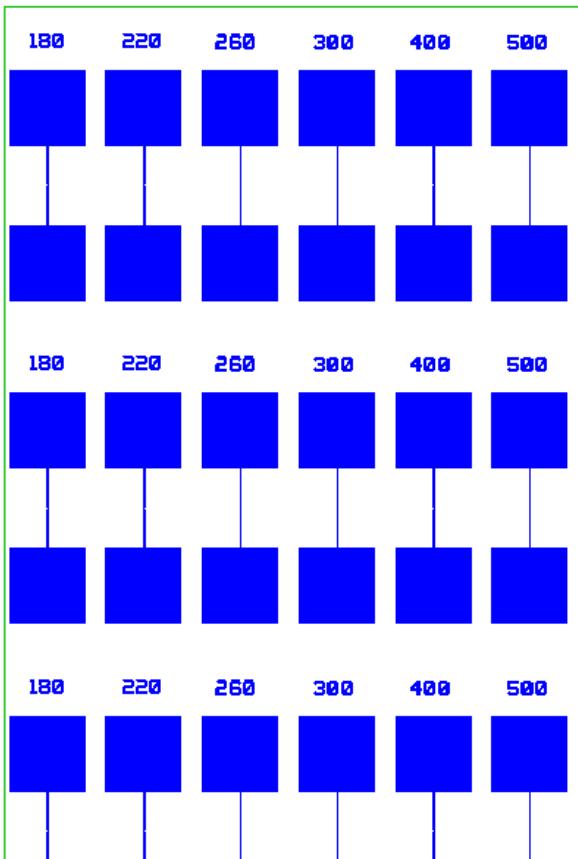
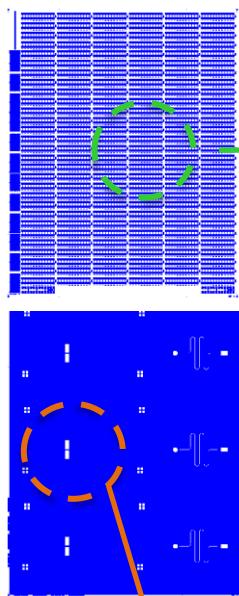
www.cqc2t.org (Centre for Quantum Computation & Communication Technology)



<https://www.dwavesys.com>

- Quantum Engineering ← adopt the ‘manufacturability mantra’



Josephson Junction Arrays

*48 junctions measured for each datum
(JJ's distributed over 25 mm x 16 mm area)*

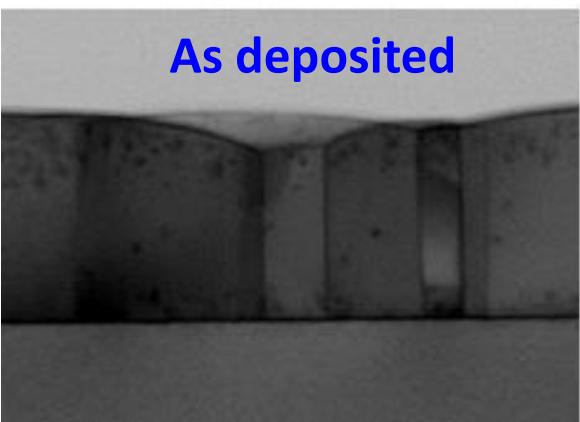
Qubit measurements at ~ 10 mK (LPS)

$$\frac{\omega_q}{2\pi} = 4.76612 \text{ GHz} \quad \& \quad 4.70267 \text{ GHz}$$

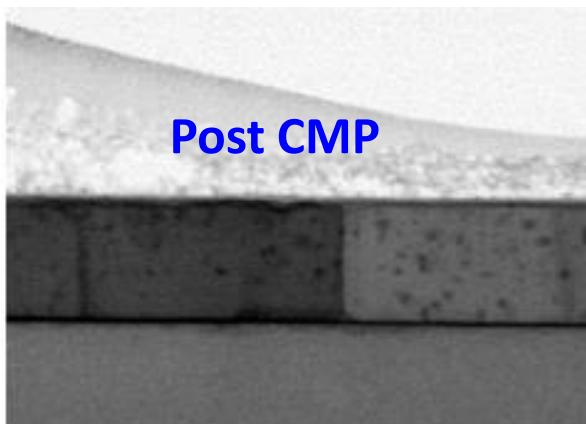
$$T_1 = 26.79 \mu\text{s} \quad \& \quad 25.93 \mu\text{s}$$

Foroozani et al, manuscript submitted (2018)

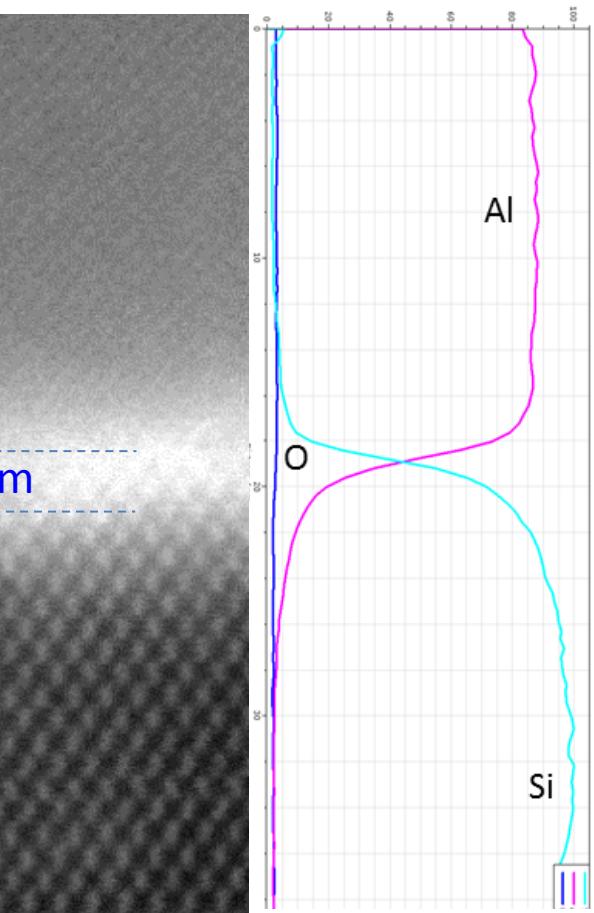
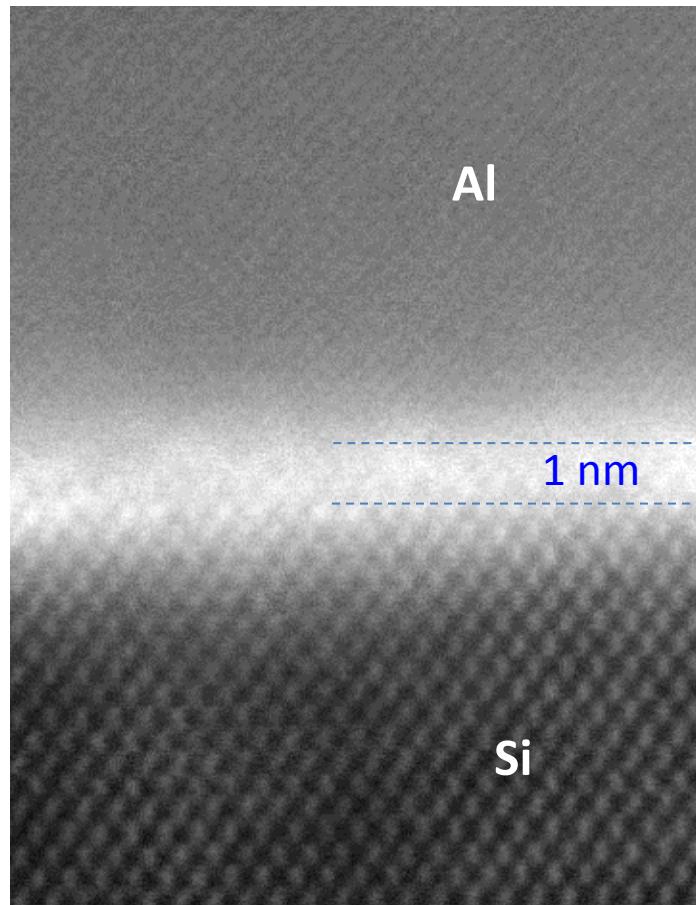
- New processes → New device architectures
- New devices → Better systems → larger horizons for imagination



As deposited



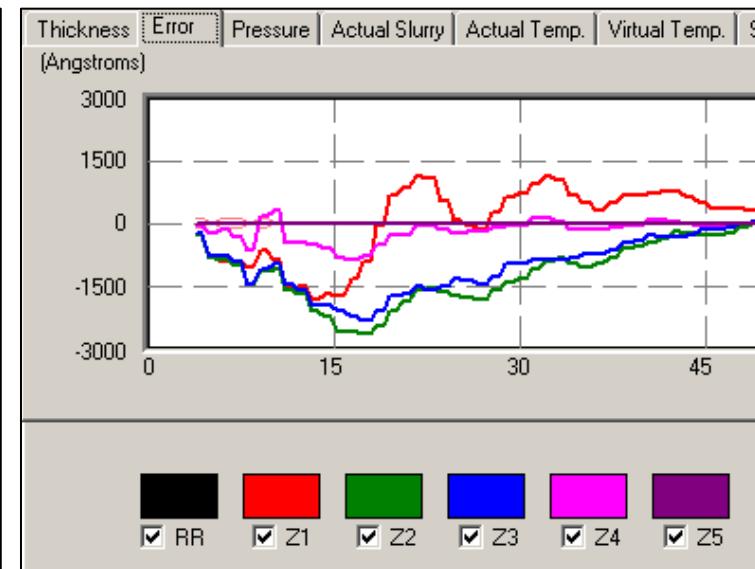
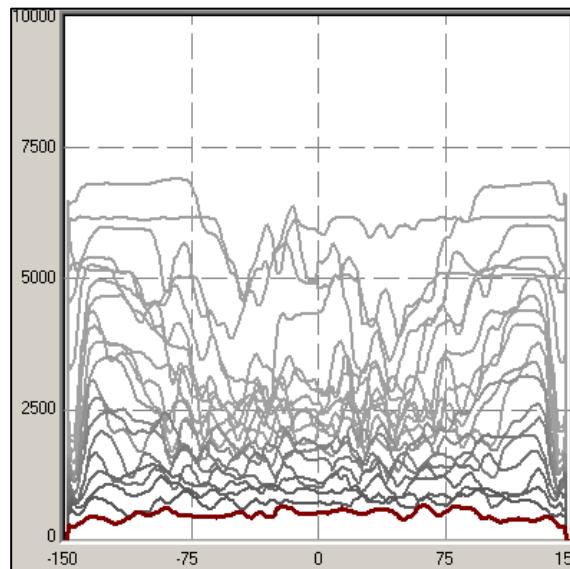
Post CMP



ECS Transactions 85(6) 151 (2018)

Metal film CMP:

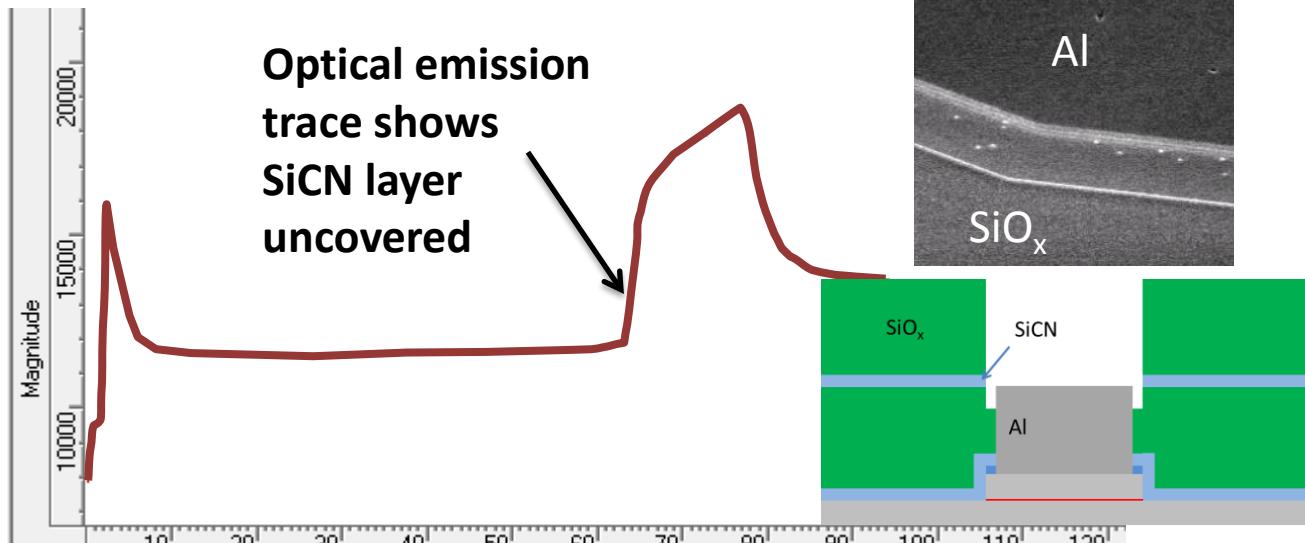
Automated adjustment
of zone pressures for
thickness uniformity



Reactive Ion Etch:

Optical endpointing
frequently harnessed to
improve processes

New 300mm tools have
chucks with multi-zone
temperature controls

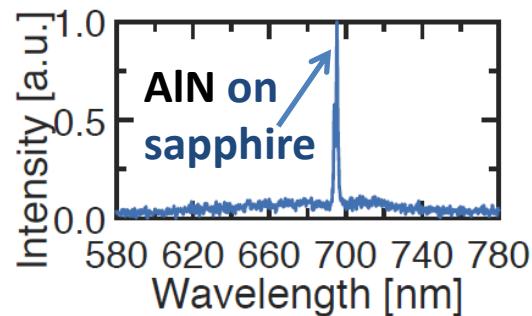


- UV-PICs with Si/SiO₂/poly AlN at 300mm scale
- In partnership with RIT (Stefan Preble), AFRL (Mike Fanto) and MIT (Dirk Englund)

Ion	λ (nm)
¹⁹⁹ Hg ⁺	282
¹⁷¹ Yb ⁺	369.5
⁸⁸ Sr ⁺	422
¹³⁸ Ba ⁺	650

Crystalline AlN on Sapphire

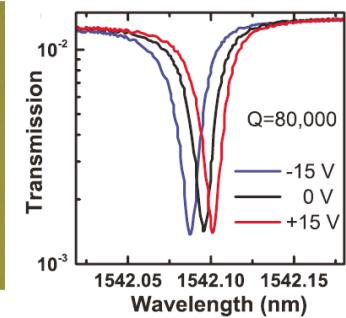
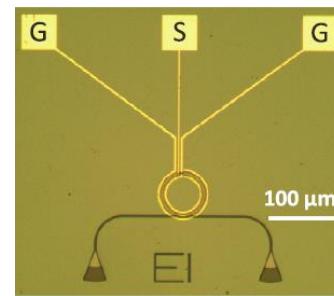
Lu et al, *Optics Express* **26** (9) 11147 (2018)



Low loss waveguides, grating couplers ... for UV

Poly AlN on Si/SiO₂

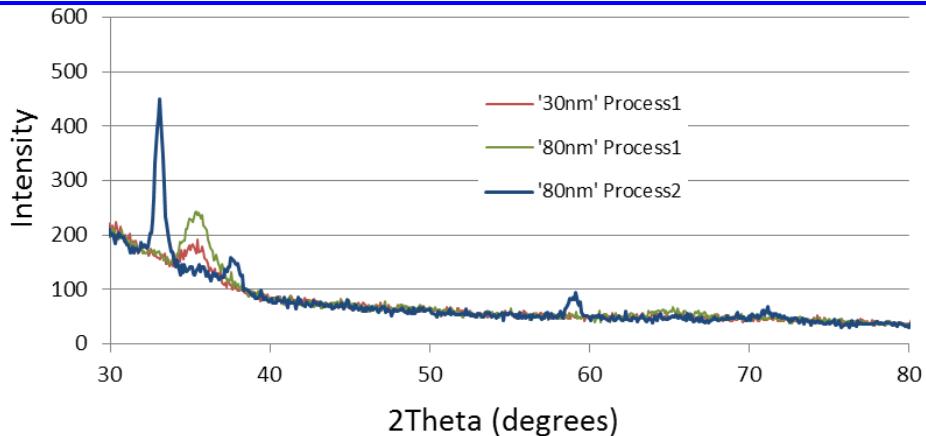
Xiong et al, *New J Phys* **14**, 095014 (2012)



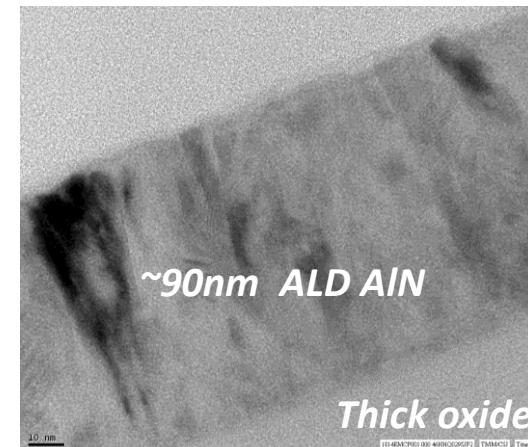
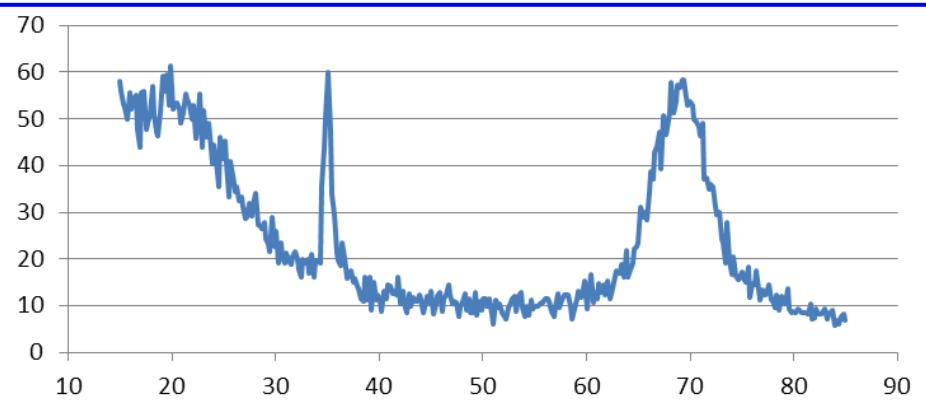
Electro-optic modulation with AlN

- AlN film characterization on 300 mm Si wafers

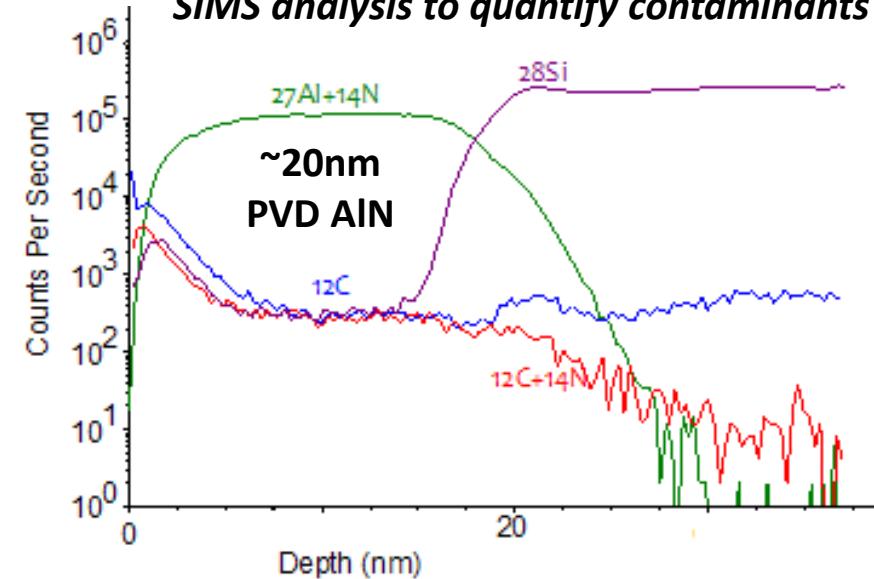
Glancing Incidence XRD from ALD AlN variants

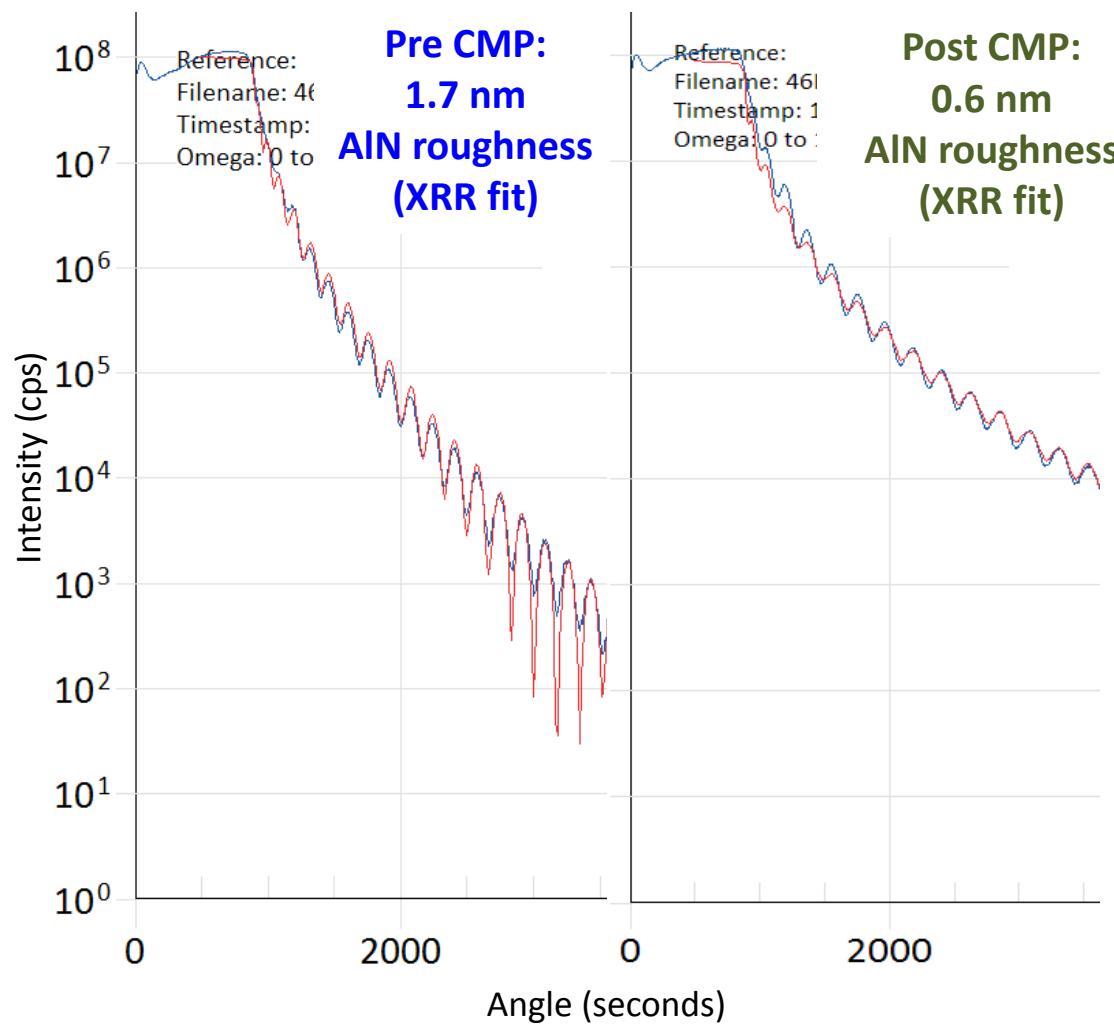


XRD spectrum from 20nm PVD-AlN film

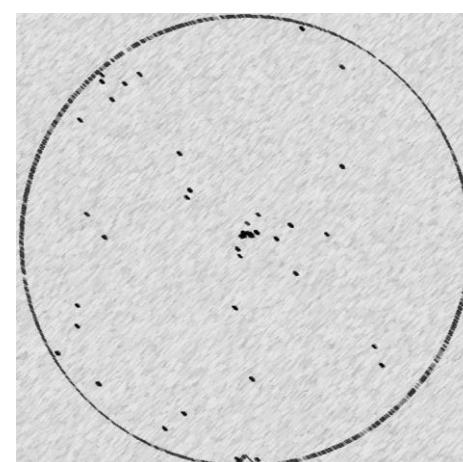
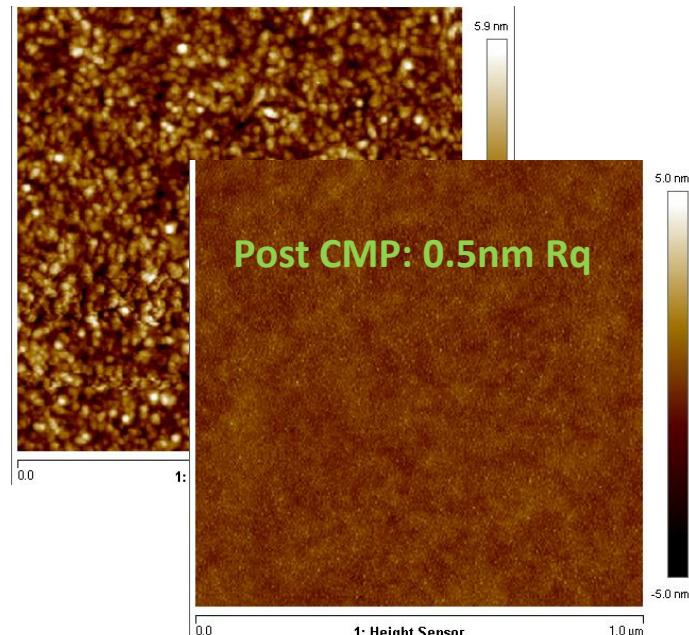


SIMS analysis to quantify contaminants





Pre CMP: 1.6nm Rq



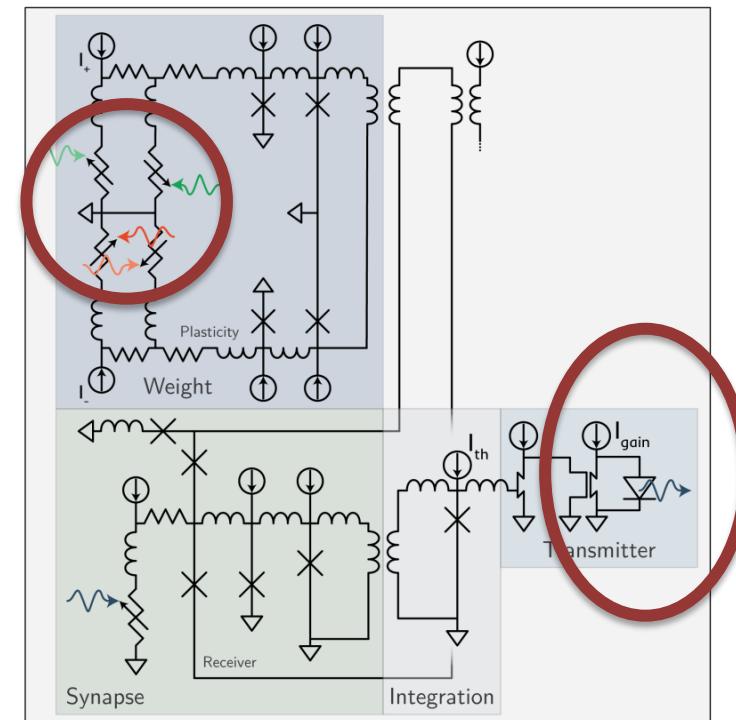
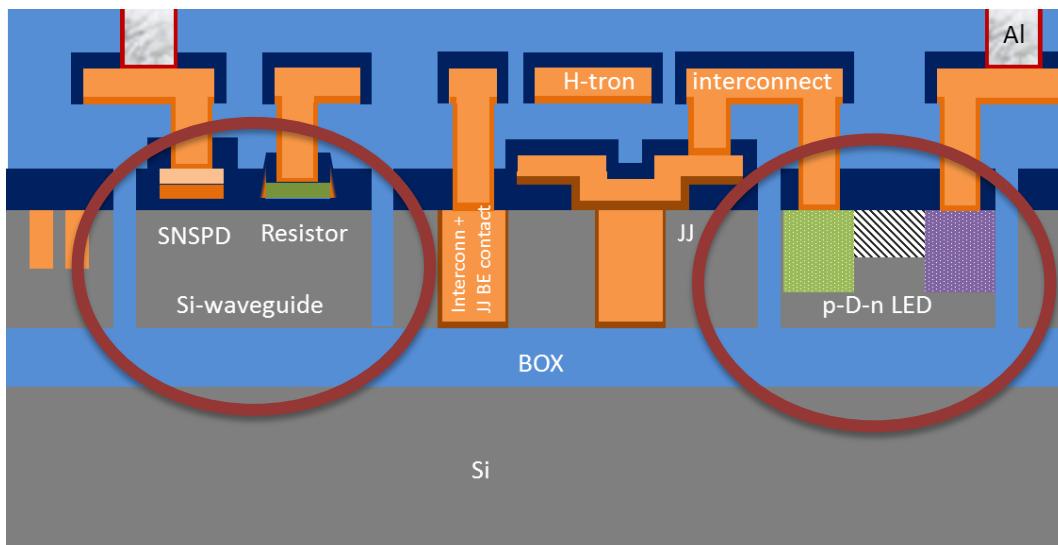
<100 defects
post CMP
(at ~0.12 um
sensitivity)

- Next: 193nm litho & RIE + Cu for RF

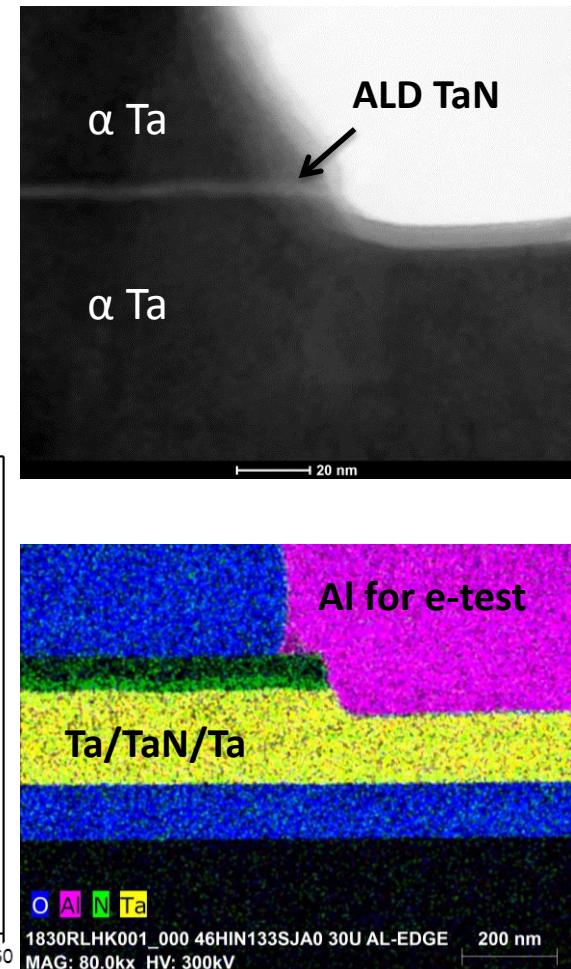
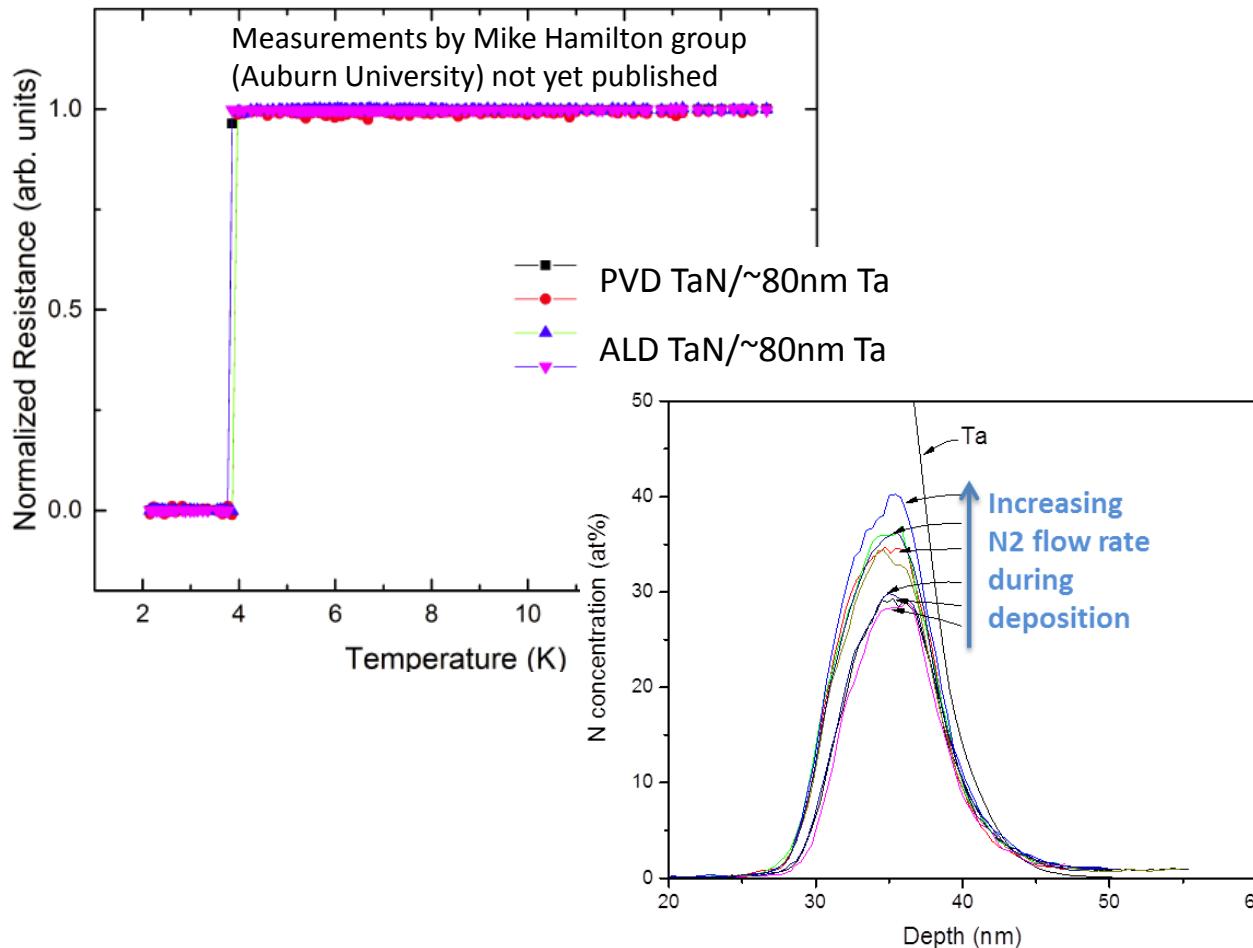
In partnership with NIST Boulder (Shainline, Buckley, Mirin, Nam) and using AFRL-funded maskset

- Josephson junctions
(fast, sub-aJ pulses!) → 30,000x faster than brain
- Cryo-photonics + SNSPDs → spikes/s/W ~ human brain

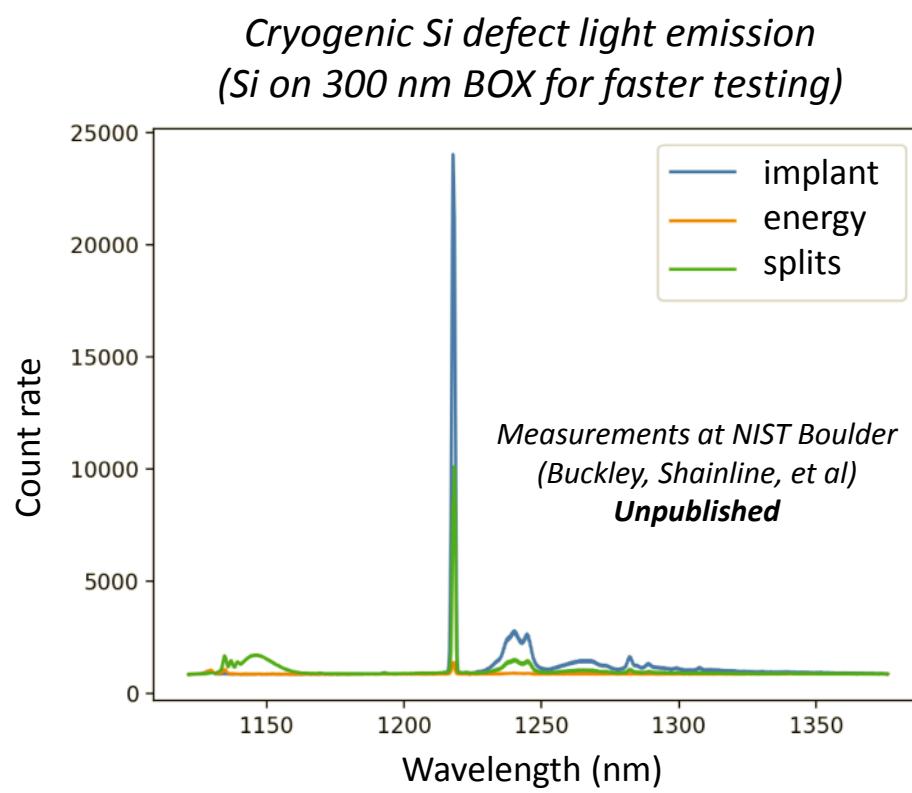
*1 cm²die: 8k neurons + 330k synapses ...
and further scalable*



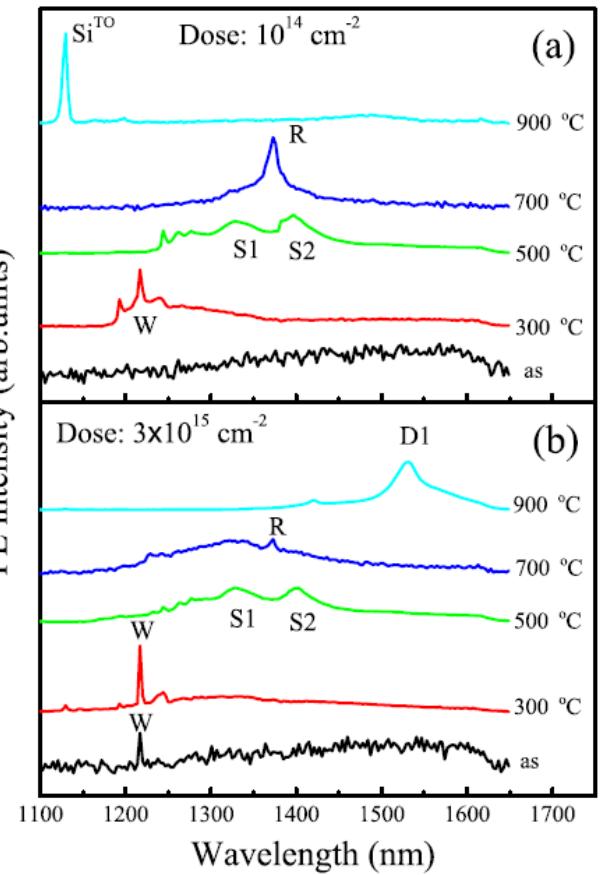
- CMOS-compatible Josephson junctions with α -Tantalum & ALD-Ta_N
- PVD Ta_N-based SNSPDs



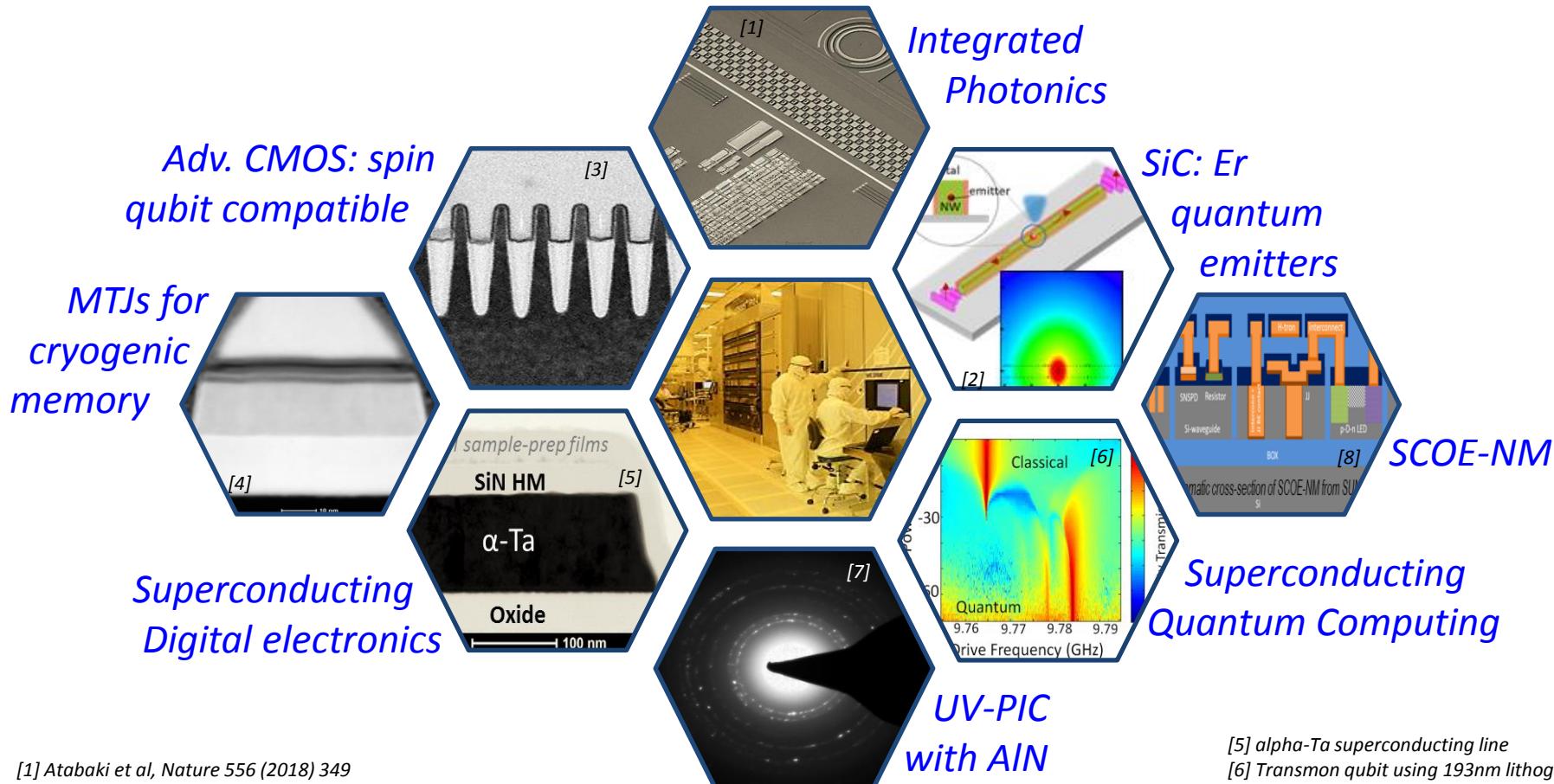
- Si-defect based IR emission into SOI waveguides



Yang et al. J. Appl. Phys. **107**, 123109 (2010)



- One Fab to Make Them All... And With Light Bind Them!



[1] Atabaki et al, *Nature* 556 (2018) 349

[2] SiC:Er research by S. Galis group

[3] 7nm CMOS test chip fab'ed at SUNY Poly

[4] MTJ fabricated at SUNY Poly, 2015

[5] α -Ta superconducting line

[6] Transmon qubit using 193nm lithography

[7] fab-friendly UV-VIS waveguide material

[8] Supercond Optoelectronic
Neuromorphic computing elements